











SN54AHCT574, SN74AHCT574

SCLS245M - OCTOBER 1995-REVISED SEPTEMBER 2014

SNx4AHCT574 Octal Transparent D-Type Latches With 3-State Outputs

Features

- Inputs are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- On Products Compliant to MIL-PRF-38535, All Parameters are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

Applications

- **Smartphone Handsets**
- **PDAs**
- **Network Switches**
- Wearable Health and Fitness Devices
- Televisions (LCDs)
- Power Infrastructures

3 Description

The SNx4AHCT574 devices are octal edge-triggered D-type flip-flops that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SSOP (20)	7.20 mm × 5.30 mm		
	TVSOP (20)	5.00 mm × 4.40 mm		
SNx4AHCT574	SOIC (20)	12.80 mm × 7.50 mm		
	PDIP (20)	25.40 mm × 6.35 mm		
	TSSOP (20)	6.50 mm × 4.40 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

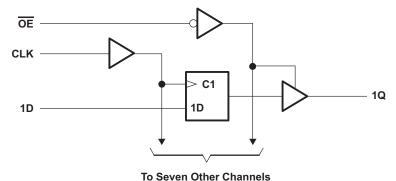




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5 Revision History

CI	hanges from Revision L (July 2003) to Revision M	Page
•	Updated document to new TI data sheet format.	1
•	Deleted Ordering Information table.	1
•	Added Military Disclaimer to Features list.	1
•		
•	Added Handling Ratings table	4
•	Changed MAX operating temperature to 125°C in Recommended Operating Conditions table	4
•	Added Thermal Information table.	5
•	Added –40°C to 125°C for SN74AHCT574 in the Electrical Characteristics table	5
•	Added $T_A = -40$ °C to 125°C for SN74AHCT574 in the Timing Requirements table	5
•	Added $T_A = -40$ °C to 125°C for SN74AHCT574 in the Switching Characteristics table	6
	Added Typical Characteristics	
•	Added Detailed Description section	8
•		
•	Added Power Supply Recommendations and Layout sections	10

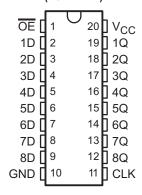
Product Folder Links: SN54AHCT574 SN74AHCT574

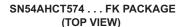
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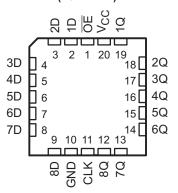


6 Pin Configuration and Functions

SN54AHCT574 . . . J OR W PACKAGE SN74AHCT574 . . . DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)







Pin Functions

F	PIN	I/O	DESCRIPTION
NO.	NAME	10	DESCRIPTION
1	ŌĒ	I	Output Enable
2	1D	I	1D Input
3	2D	I	2D Input
4	3D	I	3D Input
5	4D		4D Input
6	5D	I	5D Input
7	6D	I	6D Input
8	7D	I	7D Input
9	8D		8D Input
10	GND	-	Ground Pin
11	CLK		Clock Pin
12	8Q	0	8Q Output
13	7Q	0	7Q Output
14	6Q	0	6Q Output
15	5Q	0	5Q Output
16	4Q	0	4Q Output
17	3Q	0	3Q Output
18	2Q	0	2Q Output
19	1Q	0	1Q Output
20	V _{CC}	_	Power Pin



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	٧
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Output voltage range (2)		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through V _{CC} or GND			±50	mA

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	e	-65	150	°C
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2000	V
V _(ESD)		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		SN54AHC	T574	SN74AHC	T574	UNIT
		MIN	MAX	MIN	MAX	UNIT
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_{I}	Input voltage	0	5.5	0	5.5	V
Vo	Output voltage	0	V_{CC}	0	V_{CC}	V
I _{OH}	High-level output current		-8		-8	mA
I _{OL}	Low-level output current		8		8	mA
$\Delta t/\Delta v$	Input transition rise or fall rate		20		20	ns/V
T _A	Operating free-air temperature	– 55	125	-40	125	°C

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information

				SN74AH0	CT574			
	THERMAL METRIC ⁽¹⁾	DW	DB	DGV	N	NS	PW	UNIT
		20 PINS						
$R_{\theta JA}$	Junction-to-ambient thermal resistance	79.4	97.9	117.2	53.3	79.2	103.3	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	45.7	59.6	32.7	40.0	45.7	37.8	
$R_{\theta JB}$	Junction-to-board thermal resistance	46.9	53.1	58.7	34.2	46.8	54.3	°C/W
Ψлт	Junction-to-top characterization parameter	18.7	21.3	1.15	26.4	19.3	2.9	30/00
ΨЈВ	Junction-to-board characterization parameter	46.5	52.7	58.0	34.1	46.4	53.8	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	T _A = 25°C		SN54AHCT574		-40°C to 85°C SN74AHCT574		-40°C to 125°C SN74AHCT574		UNIT	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
V	I _{OH} = -50 μA	45.1/	4.4	4.5		4.4		4.4		4.4		V
V _{OH}	I _{OH} = −8 mA	4.5 V	3.94			3.8		3.8		3.8		V
	I _{OL} = 50 μA	45.1/			0.1		0.1		0.1		0.1	V
V _{OL}	I _{OL} = 8 mA	4.5 V			0.36		0.44		0.44		0.44	V
l _l	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1 ⁽¹⁾		±1		±1	μΑ
I _{OZ}	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5		±2.5		±2.5	μΑ
I _{cc}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40		40	μΑ
ΔI _{CC} ⁽²⁾	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5		1.5		1.5	mA
C _i	V _I = V _{CC} or GND	5 V		3	10				10			pF
Co	V _O = V _{CC} or GND	5 V		3								pF

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.

7.6 Timing Requirements

over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 2)

		T _A = 25°C		SN54AHCT574		SN74AH	CT574	T _A = -40°C to 125°C SN74AHCT574		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration, LE high	5.5		5.5		5.5		5.5		ns
t _{su}	Setup time, data before LE↓	3.5		3.5		3.5		3.5		ns
t _h	Hold time, data after LE↓	1.5		1.5		1.5		1.5		ns

⁽²⁾ This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.



7.7 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	LOAD	T _A = 25°C		SN54AHCT574		SN74AHCT574		T _A = -40°C to 125°C SN74AHCT574		UNIT	
	(OUTPUT)	(INPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	•
,			C _L = 15 pF	130 ⁽¹⁾	180 ⁽¹⁾		110 ⁽¹⁾		110		110		
f_{max}			C _L = 50 pF	85	115		75		75		75		ns
t _{PLH}	CLK	0	0 45 - 5		5.5 ⁽¹⁾	8.6(1)	1 ⁽¹⁾	10 ⁽¹⁾	1	10	1	11	
t _{PHL}	CLK	Q	C _L = 15 pF		5.5 ⁽¹⁾	8.6(1)	1 ⁽¹⁾	10 ⁽¹⁾	1	10	1	11	ns
t _{PZH}		_	0 45 5		5 ⁽¹⁾	9(1)	1 ⁽¹⁾	10.5 ⁽¹⁾	1	10.5	1	11.5	
t _{PZL}	ŌĒ	Q	$C_L = 15 pF$		5 ⁽¹⁾	9 ⁽¹⁾	1 ⁽¹⁾	10.5 ⁽¹⁾	1	10.5	1	11.5	ns
t _{PHZ}	ŌĒ	0	0 45 - 5		5.5 ⁽¹⁾	9 ⁽¹⁾	1 ⁽¹⁾	10.5 ⁽¹⁾	1	10.5	1	11.5	
t _{PLZ}	OE	Q	C _L = 15 pF		5.5 ⁽¹⁾	9 ⁽¹⁾	1 ⁽¹⁾	10.5 ⁽¹⁾	1	10.5	1	11.5	ns
t _{PLH}	OLIK	0	0 50 - 5		7	10.6	1	12	1	12	1	13	
t _{PHL}	CLK	Q	C _L = 50 pF		7	10.6	1	12	1	12	1	13	ns
t _{PZH}	0 -	Q	C 50 = E		6	11	1	12.5	1	12.5	1	13.5	
t _{PZL}	ŌĒ	Q	C _L = 50 pF		6	11	1	12.5	1	12.5	1	13.5	ns
t _{PHZ}	ŌĒ	0	C 50.75		7	10.1	1	11.5	1	11.5	1	13	
t _{PLZ}		Q	C _L = 50 pF		7	10.1	1	11.5	1	11.5	1	13	ns
t _{sk(o)}			C _L = 50 pF			1 ⁽²⁾				1			ns

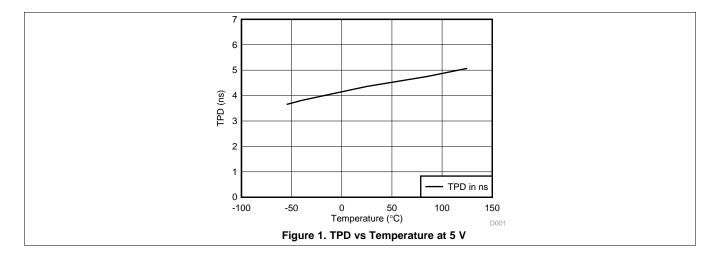
⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.8 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	TYP	UNIT	
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	28	pF

7.9 Typical Characteristics



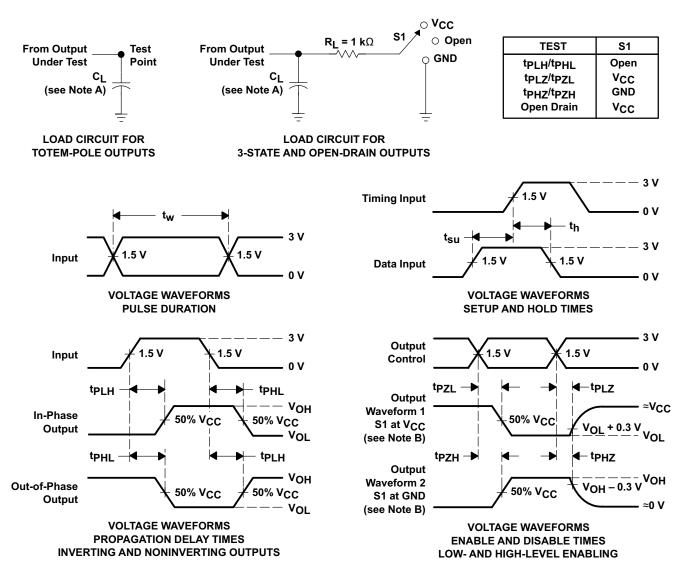
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⁽²⁾ On products compliant to MIL-PRF-38535, this parameter does not apply.



8 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 3 ns. $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

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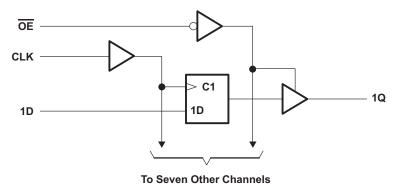
9 Detailed Description

9.1 Overview

The SNx4AHCT574 devices are octal edge-triggered D-type flip-flops that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. These devices are particularly suitable for implementing buffer registers, IO ports, bidirectional bus drivers, and working registers.

Regarding the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels of the data (D) inputs. A buffered output-enable (\overline{OE}) input places the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pull-up components.

9.2 Functional Block Diagram



9.3 Feature Description

- TTL inputs
 - Lowered switching threshold allows up translation 3.3 V to 5 V
- Slow edges reduce output ringing

9.4 Device Functional Modes

Table 1. Function Table (Each Flip-Flop)

	INPUTS		OUTPUT
ΘE	CLK	D	Q
L	↑	Н	Н
L	↑	L	L
L	H or L	Χ	Q_0
Н	Х	Χ	Z

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10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The SN74AHCT574 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8-V V_{IL} and 2-V V_{IH} . This feature makes the device ideal for translating up from 3.3 V to 5 V. Figure 4 shows this type of translation.

10.2 Typical Application

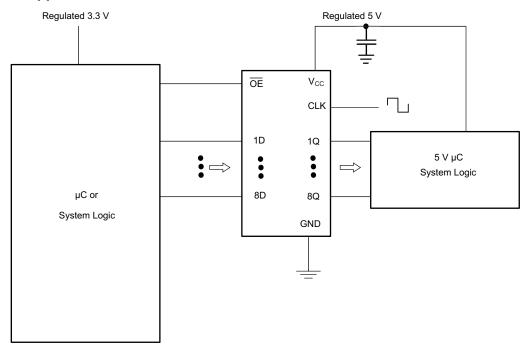


Figure 3. Typical Application Schematic

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

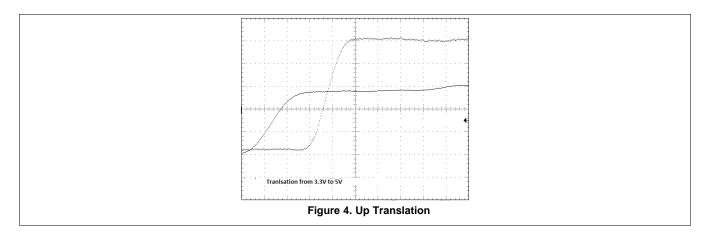
- 1. Recommended input conditions
 - Rise time and fall time specs: See (Δt/ΔV) in the Recommended Operating Conditions table.
 - Specified High and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend output conditions
 - Load currents should not exceed 25 mA per output and 75 mA total for the part.
 - Outputs should not be pulled above V_{CC}.

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Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Recommended Operating Conditions table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μF bypass capacitor is recommended. If there are multiple V_{CC} pins, 0.01 μF or 0.022 μF is recommended for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1 μF and 1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in Figure 5 are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} ; whichever makes more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the IO's so they cannot float when disabled.

12.2 Layout Example

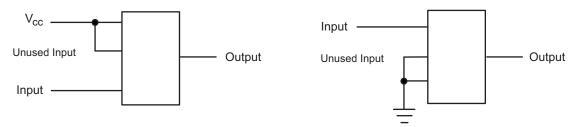


Figure 5. Layout Diagram

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13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54AHCT574	Click here	Click here	Click here	Click here	Click here	
SN74AHCT574	Click here	Click here	Click here	Click here	Click here	

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9685301Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9685301Q2A SNJ54AHCT 574FK	Samples
5962-9685301QRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QR A SNJ54AHCT574J	Samples
5962-9685301QSA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QS A SNJ54AHCT574W	Samples
SN74AHCT574DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574DBRE4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574DGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT574	Samples
SN74AHCT574DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT574	Samples
SN74AHCT574N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT574N	Samples
SN74AHCT574NSR	ACTIVE	so	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT574	Samples
SN74AHCT574PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574PWG4	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HB574	Samples
SN74AHCT574PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SNJ54AHCT574FK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9685301Q2A SNJ54AHCT 574FK	Samples
SNJ54AHCT574J	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QR A	Samples

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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							`,			SNJ54AHCT574J	
SNJ54AHCT574W	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QS A SNJ54AHCT574W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AHCT574, SN74AHCT574:

PACKAGE OPTION ADDENDUM

www.ti.com 10-Jun-2022

● Catalog : SN74AHCT574

• Military : SN54AHCT574

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT574DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHCT574DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT574DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHCT574NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AHCT574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHCT574PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT574DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74AHCT574DGVR	TVSOP	DGV	20	2000	356.0	356.0	35.0
SN74AHCT574DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHCT574NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74AHCT574PWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHCT574PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AHCT574PWRG4	TSSOP	PW	20	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9685301Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9685301QSA	W	CFP	20	1	506.98	26.16	6220	NA
SN74AHCT574DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74AHCT574N	N	PDIP	20	20	506	13.97	11230	4.32
SN74AHCT574PW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74AHCT574PWG4	PW	TSSOP	20	70	530	10.2	3600	3.5
SNJ54AHCT574FK	FK	LCCC	20	1	506.98	12.06	2030	NA
SNJ54AHCT574W	W	CFP	20	1	506.98	26.16	6220	NA

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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